

/ Descriptions

TO-220 N MOS N-CHANNEL MOSFET in a TO-220 Plastic Package.

/ Features

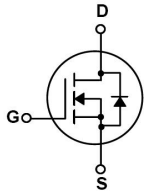
$R_{DS(on)}$ C_{rss}
Low $R_{DS(on)}$, low gate charge, low C_{rss} , fast switching.

/ Applications

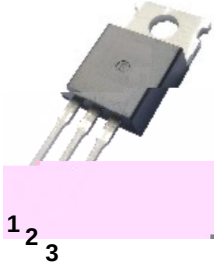
DC/DC

Suited for low voltage applications such as automotive, DC/DC Converters, and high efficiency switching for power management in portable and battery operated products.

/ Equivalent Circuit



/ Pinning



PIN1 G PIN 2 D PIN 3 S

/ h_{FE} Classifications & Marking

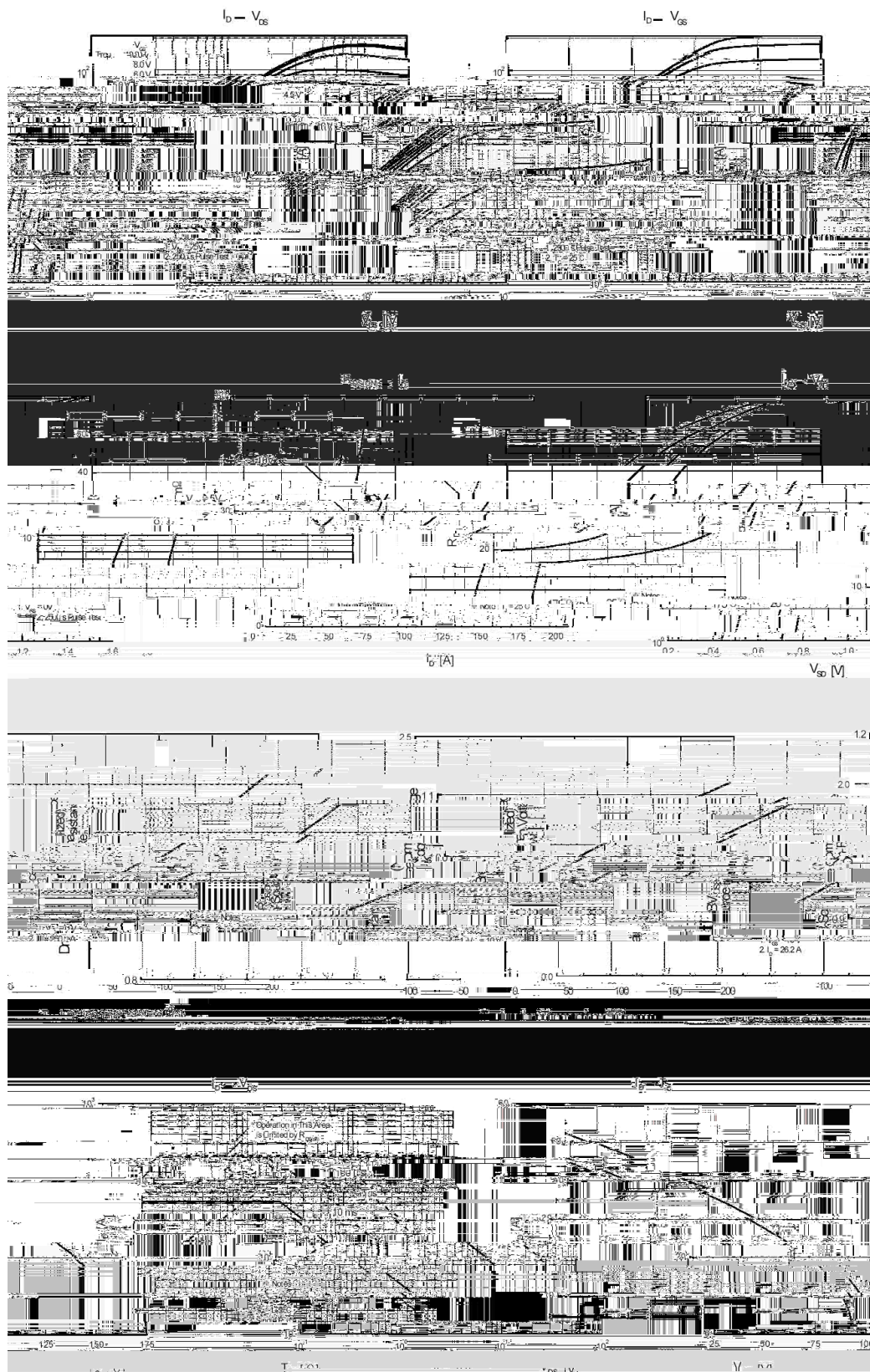
See Marking Instructions.

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	60	V
Drain Current	$I_D(T_c=25^\circ\text{C})$	50	A
Drain Current	$I_D(T_c=100^\circ\text{C})$	35.4	A
Drain Current - Pulsed	I_{DM}	200	A
Gate-Source Voltage	V_{GS}	± 20	V
Single Pulsed Avalanche Energy	E_{AS}	490	mJ
Avalanche Current	E_{AR}	12	mJ
Power Dissipation	$P_D(T_c=25^\circ\text{C})$	120	W
Operating Temperature Range	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

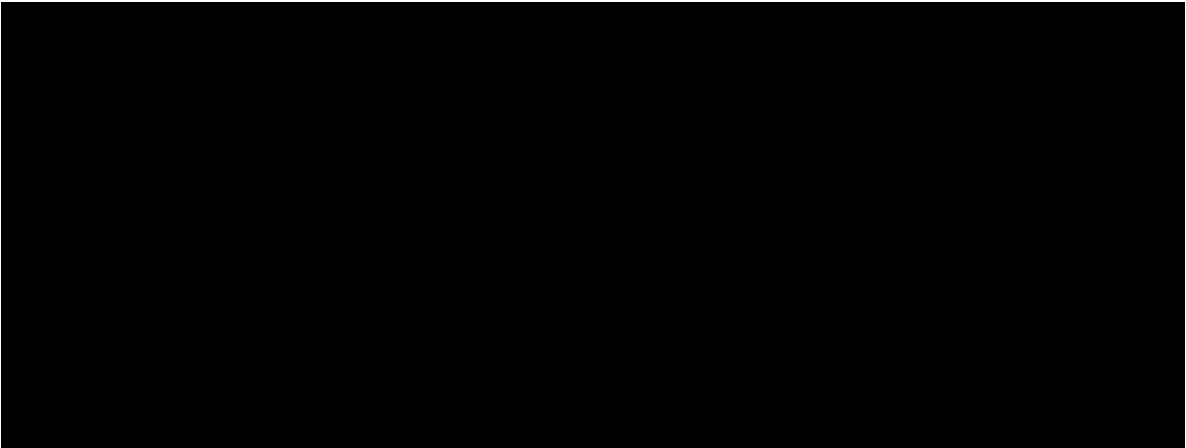
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250\text{ A}$	60			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V$ $V_{GS}=0V$			1.0	A
		$V_{DS}=48V$ $T_C=150$			10	
Gate-Body Leakage Current, Forward	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			± 0.1	A
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\text{ A}$	2		4	V
Total Gate Charge	Q_g	$V_{DS}=48V$ $I_D=50A$ $V_{GS}=10V$		32	42	nC
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=25A$		0.018	0.022	
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=50A$			1.5	V
Input Capacitance	C_{iss}	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0MHz$		1050	1365	pF
Output Capacitance	C_{oss}			460	600	

47ev64 48101066.76 206.9606804 22 13()897DS

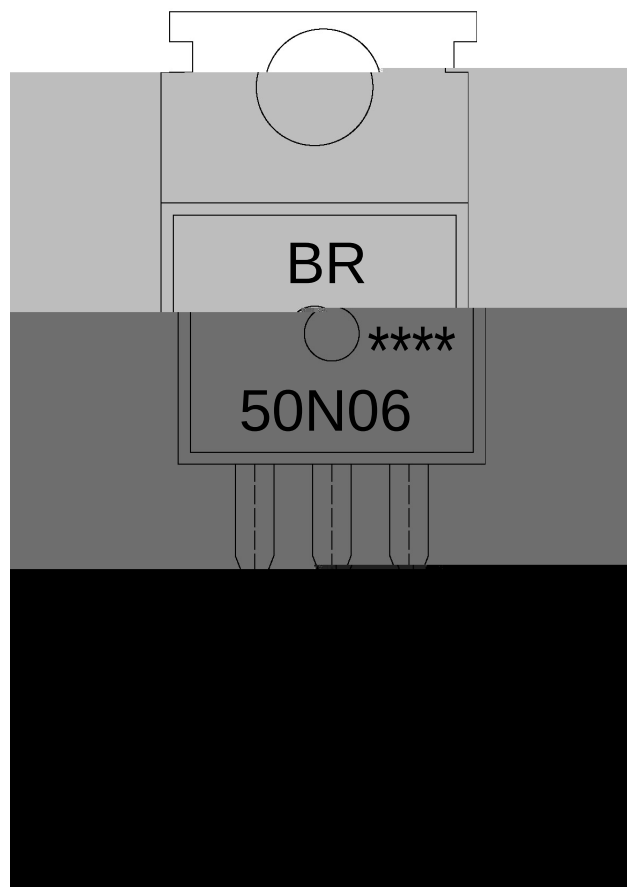
/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions



BR

50N06

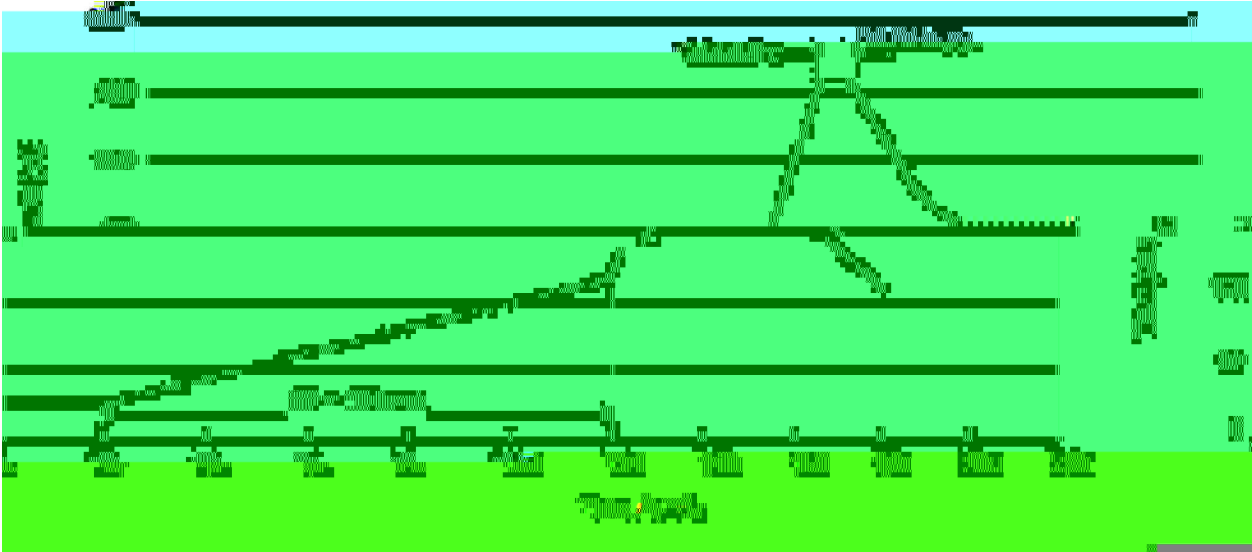
Note:

BR: Company Code

50N06: Product Type Code

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;
- 2

255±5

5±0.5sec;
- 3

2 10

/sec.
- 1.Preheating:25~150

, Time:60~90sec.
- 2.Peak Temp.:255±5

, Duration:5±0.5sec.
3. Cooling Speed: 2~10

/sec.

/ Resistance to Soldering Heat Test Conditions

270±5

10±1 sec.

Temp.:270±5

Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units					Dimension (unit mm ³)		
	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Bag	Inner Box	Outer Box
			2,000	5	10,000	135×190	237×172×102	560×245×195